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Corrigendum to "Van der Waals materials for HOT infrared detectors: A review" [Opto-Electronics Review 30 (2022) e140551]

Antoni Rogalski

Institute of Applied Physics, Military University of Technology, 2 Kaliskiego St., 00-908 Warsaw, Poland

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The author regrets that an error in equation (10) (detector thickness, t, should be removed) consequently affected the erroneous form of equation (13).

The correct version of the expression (10) is in the form of

$$G_{th} = \frac{N_{min}}{\tau} ,$$

which leads to expression (13) in the form of

$$D^* \propto \left(\frac{\alpha}{G_{th}}\right)^{1/2} = \left(\frac{\alpha N_{maj} \tau}{n_i^2}\right)^{1/2} = \left(\frac{\sqrt{N_{maj}}}{n_i}\right) \sqrt{\alpha \tau}$$

i.e. the detectivity is proportional to $\sqrt{\alpha\tau}$; not proportional to $\alpha\sqrt{\tau}$ as stated in the source paper.

As a result of the above correction, the last two paragraphs of section 4 have been amended as shown below:

Considering the experimental data collected in Figs. 4, 5 and 7, it is possible to compare the estimated $\sqrt{\alpha\tau}$ values for

HgCdTe ($\alpha = 2 \times 10^3 \text{ cm}^{-1}$, $\tau = 10^{-3} \text{ s}$) with those for 2D TMD materials ($\alpha = 2 \times 10^5 \text{ cm}^{-1}$, $\tau = 10^{-9} \text{ s}$). For HgCdTe, it is equal to 1.4 (s/cm)^{1/2} while for TMD materials: $1.4 \times 10^{-2} \text{ (s/cm)}^{1/2}$, which is two orders of magnitude smaller. Note that the comparison of $\sqrt{\alpha \tau}$ values is for semiconductors with significantly different energy gaps. For a hypothetical 2D material with a narrow energy gap (of the order of 0.1 eV which is the case of HgCdTe), the absorption coefficient would be smaller (about one order of magnitude), resulting in a much smaller $\sqrt{\alpha \tau}$ for the hypothetical 2D materials compared to the HgCdTe material.

To summarize the discussion in this section, it can be concluded that, considering the $\sqrt{\alpha\tau}$ paradigm, HgCdTe is a better material for the active area of LWIR detectors compared to 2D TMD materials.

The corrections made changed the performance figure-ofmerit values for the materials used in the fabrication of infrared detectors, but do not affect the qualitative conclusions cited throughout the paper.

^{*}Corresponding author at: antoni.rogalski@wat.edu.pl